## Weak ferromagnetism induced by the external field above $T_N$ in Gd<sub>z</sub>CuO<sub>4</sub>

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A detailed study of the temperature and field dependence of the dc magnetization near the antiferromagnetic (AF) transition in Gd<sub>2</sub>CuO<sub>4</sub> shows the presence of field-induced weak ferromagnetism (WF) well above the Néel temperature  $T_N$  ac susceptibility measurements indicate  $T_N=266(3)$  and 282(3) K, for single crystals and ceramic samples, respectively. The shift of the electron-spin-resonance line of the Gd<sup>3+</sup> ions as a function of temperature T,  $\delta H_r(T)$ , is compared with the static internal field  $H_i(T)$ , which describes the coupling between the paramagnetic Gd lattice and the WF component of the Cu moments. Both  $\delta H_r(T)$  and  $H_i(T)$  show that the WF persists up to  $\approx 50$  K above  $T_N$ . The initial susceptibility (for H < 100 G) presents a contribution in excess of the paramagnetism of Gd ions. For  $T \ge T_N$ , it decays as  $K(T-T_N)^{-1}$ , with K=0.20(3) emu K mol. The relationship between this result and the strong two-dimensional AF correlations in these cuprates is discussed.

The R<sub>2</sub>CuO<sub>4</sub> cuprates of heavy rare earths (R =Gd,Tb,...,Tm) present weak ferromagnetism (WF) below the antiferromagnetic Néel temperature  $T_N$  due to a small canting of the Cu sublattice caused by Dzyaloshinkii-Moriya (DM) interactions.<sup>1-3</sup> Different experimental features characterize<sup>4</sup> the complex magnetic behavior of these materials around  $T_N$ : a nonzero spontaneous magnetization  $M_s(T)$  linearly extrapolated from the high-field magnetization, a sharp peak of the dc and ac low-field susceptibilities, a shift of the electron-spinresonance (ESR) spectrum of the Gd ions  $\delta H_r(T)$ , and the presence of a low-field microwave absorption. As was pointed out in Ref. 5, the onset of both  $M_s$  and  $\delta H_r$  occurs for  $Gd_2CuO_4$  and  $Gd_{2-x}Ce_xCuO_4$  at a temperature well above the  $T_N$  determined from the peak of the low-field magnetization. An observation of WF above  $T_N$  has also been recently reported<sup>6</sup> for Y<sub>2</sub>CuO<sub>4</sub>. We present here a detailed study of the WF transition in Gd<sub>2</sub>CuO<sub>4</sub> through ac susceptibility, dc magnetization, and ESR measurements, analyzing the effects of magnetic coupling between the R ions and the Cu lattice.

Single crystals were grown in Pt crucibles using a flux technique.<sup>1</sup> All samples had the Nd<sub>2</sub>CuO<sub>4</sub>-type<sup>7</sup> crystal structure, usually identified as T'. Typical crystals were thin platelets ( $2 \times 2 \times 0.1 \text{ mm}^3$ ) oriented perpendicular to the *c* axis. Ceramic samples prepared from pressed pellets of the corresponding oxides were also measured when larger samples were needed. dc magnetization measurements were performed using either a vibrating sample magnetometer, a Quantum Design superconducting quantum interference device (Squid) magnetometer, or a homemade

Faraday balance magnetometer. ac susceptibility measurements were carried out in a Lake Shore susceptometer and electron paramagnetic resonance in an ESP 300 Bruker spectrometer for the X band (9 GHz) and a modified Varian V4500 for the Q band (35 GHz).

The ac susceptibility  $\chi_{ac}(T)$ , measured with an excitation field of 1 G, presents a sharp maximum at 266(3) and 282(3) K for the single-crystal and ceramic samples, respectively.<sup>8</sup> The temperature of the peak is frequency independent in the measured range (10–1000 Hz) and agrees with that of the low-field dc susceptibility.<sup>1</sup> We define  $T_N$  as the temperature of this peak.

Well above  $T_N$  (T > 330 K), the dc magnetization  $M_{dc}(T)$  presents a paramagnetic behavior with a Curie-Weiss constant determined essentially by the Gd<sup>3+</sup> moments in the  ${}^{8}S_{7/2}$  ground state.<sup>1</sup> At lower temperatures, the high-field differential susceptibility,  $\chi_{\text{diff}} \equiv \partial M_{\text{dc}}(T)/$  $\partial H|_{H \to \infty}$  still follows a Curie-Weiss law but  $M_{\rm dc}(H,T)$ extrapolates to a finite value  $M_s(T)$ , associated with the WF of the system.<sup>1,3</sup>  $M_s(T)$ , determined by a linear extrapolation from the measurement of  $M_{dc}(T)$  in the range between 1 and 12.5 kG, starts to develop at about 310 and 330 K for the single crystal and ceramic samples, respectively.<sup>1,5</sup> A comparison with the temperature dependence of the low-field measurements determines a temperature range  $(T_N, T_N + 50 \text{ K})$ , where the WF is strongly dependent on the applied magnetic field. We have examined in detail the field and temperature dependence of  $M_{dc}(T)$  in this temperature interval.

The high-field dc magnetization (H > 1000 G) may be described by a linear dependence,  $M_{dc}(H,T) = M_s(T)$ 



FIG. 1. (a) Static internal field  $H_i(T)$  and (b) shift of the Gd<sup>3+</sup> ESR line  $\delta H_r(T)$  measured at 9.3 GHz for a Gd<sub>2</sub>CuO<sub>4</sub> single crystal. The arrow corresponds to the Néel temperature determined from the  $\chi_{dc}(T)$  peak.

 $+\chi_{Gd}(T)H$ . Here  $M_s(T)$  has two contributions,  $M_s(T)$  $=M_{Cu}(T)+\chi_{Gd}(T)H_i(T)$ , arising, respectively, from the canting of the ordered Cu moments and the polarization of the paramagnetic Gd ions through an internal magnetic field. As determined in Ref. 9,  $H_i(T) = \lambda' M_{Cu}(T)$ , with  $\lambda' = -1.8(5) \times 10^5$  G Cu atom/ $\mu_B$ . We present in Fig. 1(a) values determined for  $H_i(T)$  in a single crystal from data taken with applied fields larger than 1 kG. In the low-field limit,  $M_{dc}(H,T)$  is linear in H above  $T_N$  with a slope that increases strongly as  $T_N$  is approached, as shown in Fig. 2. Below  $T_N$  a small remanent magnetization develops. We have measured the initial susceptibility  $\chi_i(T) = dM_{dc}(H,T)/dH|_{H\to 0}$  in a 144 mg ceramic sample, which shows a peak in the ac susceptibility at  $T_N = 282(3)$ K. For applied fields up to 100 G we found a linear behavior for  $T > T_N$ . In Fig. 3 we compare  $\chi_i(T)$  with the freeion susceptibility of the Gd<sup>3+</sup> moments  $\chi_{Gd}(T)$ . The excess susceptibility  $[\chi_i(T) - \chi_{Gd}(T)]$ , tends to diverge near



FIG. 2. Magnetic-field dependence of  $[M_{dc}(H,T) - 2\chi_{Gd}(T)H]$  measured for a Gd<sub>2</sub>CuO<sub>4</sub> ceramic sample.



FIG. 3. Initial susceptibility  $\chi_i(T) = dM_{dc}(T)/dH|_{H\to0}$ , measured for a Gd<sub>2</sub>CuO<sub>4</sub> ceramic sample with applied fields up to 100 G.  $\blacktriangle$  correspond to ac susceptibility measurements. The dashed line is the paramagnetic contribution ( $\chi_0 + 2\chi_{Gd}$ ), and the solid line represents the fitting including the  $K/(T-T_N)$  term.

 $T_N$  and may be described by a  $K(T-T_N)^{-1}$  law, with K=0.20(2) emu K/mol.

As we approach  $T_N$ , the field for resonance  $H_r$  of the Gd<sup>3+</sup> ESR spectrum shifts<sup>4</sup> from its high-temperature value, which corresponds to the free-ion gyromagnetic factor, g=1.99. The onset of this shift has been observed<sup>5</sup> at temperatures higher than  $T_N$ . Since our ESR experiments require the use of magnetic fields larger than 1 kG ( $H_r$ ) = 3.3 kG for the X band and  $H_r$  = 13.2 kG for the Q band, when g=2), significant amounts of field-induced WF are expected to be present in these experiments, which results in the observation of the ESR shift  $\delta H_r(T)$  up to temperatures much higher than  $T_N$ . Our measurements indicate that  $\delta H_r(T)$  presents a similar temperature dependence for X and Q bands. In Fig. 1 we compare the results for the X band with the internal field  $H_i(T)$ , determined from  $M_{\rm dc}(T)$  measurements for 1 kG < H < 12.5 kG. The difference in magnitude (a factor  $\approx 2$ ) has been associated<sup>10</sup> with the dynamic coupling between the Gd and Cu moments.

The field-induced WF above  $T_N$  may be analyzed in terms of a free energy for the coupled system,

$$\mathcal{F} = \left(\frac{A(T)}{2}\right) |\mathbf{l}|^2 + \left(\frac{1}{2\chi_0}\right) |\mathbf{m}|^2 + \boldsymbol{\beta} \cdot (\mathbf{l} \times \mathbf{m}) + \left(\frac{C}{4}\right) |\mathbf{l}|^4 + \left(\frac{1}{4\chi_{Gd}}\right) |\mathbf{M}_{Gd}|^2 + \lambda' \mathbf{M}_{Gd} \cdot \mathbf{m} - (\mathbf{m} + \mathbf{M}_{Gd}) \cdot \mathbf{H},$$
(1)

where  $\mathbf{m} = (\mathbf{M}_1 + \mathbf{M}_2)/2$  and  $\mathbf{l} = (\mathbf{M}_1 - \mathbf{M}_2)/2$  are the uniform and staggered magnetizations of the Cu lattice, respectively.  $\mathbf{M}_1$  and  $\mathbf{M}_2$  are the two antiferromagnetic sublattices of the Cu system. The third term,  $\boldsymbol{\beta} \cdot (\mathbf{l} \times \mathbf{m})$ , represents the antisymmetric exchange interaction within the Cu planes. The Gd sublattice is coupled to the uniform Cu magnetization through the term  $\lambda' \mathbf{M}_{Gd} \cdot \mathbf{m}$ . For  $\lambda' = 0$ this corresponds to the two-sublattice description of a canted antiferromagnet.<sup>11</sup> When  $\mathbf{H} \perp \boldsymbol{\beta}$ ,  $\mathbf{m}$  is parallel to  $\mathbf{H}$  and represents a WF component. In this case  $\beta$ , l, and H are mutually perpendicular. We may define then a reference frame such that  $\mathbf{m} = m\hat{x}$ ,  $\mathbf{l} = l\hat{y}$ , and  $\beta = \beta \hat{z}$ . The equilibrium conditions are given by

$$\frac{\partial \mathcal{F}}{\partial m_{x}} = \left(\frac{1}{\chi_{0}}\right)m - H + \lambda' M_{\text{Gd}} - \beta l = 0,$$

$$\frac{\partial \mathcal{F}}{\partial M_{\text{Gd},x}} = \left(\frac{1}{2\chi_{\text{Gd}}}\right)M_{\text{Gd},x} - H + \lambda' m = 0, \qquad (2)$$

$$\frac{\partial \mathcal{F}}{\partial l_{x}} = A(T)l + Cl^{3} - \beta m = 0.$$

We may solve this set of nonlinear equations in the vicinity of the magnetic transition by taking into account that  $|\mathbf{m}|$ ,  $|\mathbf{l}|$ , and  $|\mathbf{M}_{Gd}|$  are all small quantities and thus making a series expansion in powers of the applied field H. The Néel temperature  $T_N$  is determined by the zero of the determinant of the linearized equations,

$$\Delta(T_N) = A(T_N) (1 - 2\lambda'^2 \chi_0 \chi_{\rm Gd}) - \beta^2 \chi_0 = 0, \qquad (3)$$

where we may write, as usual,  $\Delta(T) \simeq \nu(T - T_N)$  for  $T \approx T_N$ . For  $T > T_N$ , the resulting total magnetization is given by

$$m + M_{Gd} \cong [\chi_0 + 2\chi_{Gd}(T) + 2\lambda'\chi_0\chi_{Gd} \\ \times (\lambda'\chi_0 + 2\lambda'\chi_{Gd} - 2)/(1 - 2\lambda'^2\chi_0\chi_{Gd}) \\ + \beta^2\chi_0^2(1 - 2\lambda\chi_{Gd})^2/\nu(1 - 2\lambda'^2\chi_0\chi_{Gd}) \\ \times (T - T_N)]H.$$
(4)

The first two terms correspond to the susceptibility of the uncoupled Cu and Gd lattices, respectively. The third term describes their magnetic coupling, and is expected to contribute less than 3% of  $\chi_{Gd}(T_N)$ . The last term gives a field-induced weak ferromagnetic component arising from the DM interaction. Notice that this last term varies as  $K(T-T_N)^{-1}$ , in the same way as the excess contribution measured for  $M_{dc}(T)$ . This kind of contribution was originally reported by Borovick-Romanov and Ozhogin<sup>11</sup> for MnCO<sub>3</sub> and also found<sup>6</sup> recently for Y<sub>2</sub>CuO<sub>4</sub>.

In the case of  $Y_2CuO_4$ , only the Cu lattice contributes to the WF and  $K=\beta^2\chi_0^2/\nu=0.055(6)$  emu K/mol. The main difference in Gd<sub>2</sub>CuO<sub>4</sub> is the enhancement factor  $[1-2\lambda'\chi_{Gd}(T_N)]^2 \approx 7$ , that appears due to the coupling to the paramagnetic lattice. The factor  $[1-2\lambda'^2\chi_0\chi_{Gd}(T_N)]$ is very close to unity for  $T \approx T_N$ . Values for  $\beta\chi_0$  may be derived<sup>11</sup> from the low-temperature value  $M_{Cu}(0)$  $=\beta\chi_0M_0$ , where  $M_0\approx 0.4\mu_B/Cu$  atom is the Cu magnetic moment in the antiferromagnetic lattice. In the case of Y<sub>2</sub>CuO<sub>4</sub>, a value of  $\beta \chi_0 = 0.025(4)$  has been reported.<sup>6</sup> For Gd<sub>2</sub>CuO<sub>4</sub>, we estimate  $\beta \chi_0 = 0.009(4)$  from the Cu magnetization,<sup>9</sup>  $M_{Cu}(0) = (3.5 \pm 1.5) \times 10^{-3} \mu_B/Cu$  atom. However, the smaller WF in Gd<sub>2</sub>CuO<sub>4</sub> is enhanced in the expression for K by the Gd-Cu coupling. Using these values we have estimated  $v^{-1}$ (Gd<sub>2</sub>CuO<sub>4</sub>)  $\approx 350$  emu K/mol, although with a large uncertainty due to the experimental error in the determination of  $M_{Cu}$ .

This value for  $v^{-1}$  is of the same order of magnitude as that found<sup>6</sup> for Y<sub>2</sub>CuO<sub>4</sub> ( $v^{-1} \approx 100 \text{ emu K/mol}$ ). As mentioned in Refs. 6 and 11,  $v^{-1}$  is related to the staggered susceptibility of the system, which in a mean-field approximation would be given by  $v^{-1} = C_m$ , where  $C_m$  is the Curie constant of the antiferromagnetic species. If the values for  $v^{-1}$  were analyzed in such a way, they would correspond to large effective moments (30–50 $\mu_B$ ). This large staggered susceptibility may be related to the strong 2D magnetic correlations present in the CuO<sub>2</sub> planes near  $T_N$ , as was discussed in Ref. 12 for La<sub>2</sub>CuO<sub>4</sub>. This large staggered magnetization would also be responsible for the saturation of the WF component above  $T_N$  for moderate magnetic fields, as shown in Fig. 2.

The authors wish to thank Professor V. Ozhogin for his very helpful suggestions. Partial support received from the National Science Foundation (NSF-DMR-9117212 and NSF-INT-9202813), the U.S. Department of Energy, the Consejo Nacional de Investigaciones de Argentina, and the Ministerio de Educación y Ciència de España is also acknowledged.

- <sup>1</sup>J. D. Thompson, S.-W. Cheong, S. E. Brown, Z. Fisk, S. B. Oseroff, M. Tovar, D. C. Vier, and S. Schultz, Phys. Rev. B **39**, 6660 (1989).
- <sup>2</sup>H. Okada, M. Takano, and Y. Takeda, Phys. Rev. B 42, 6813 (1990).
- <sup>3</sup>M. Tovar, X. Obradors, F. Pérez, S. B Oseroff, R. J. Duro, J. Rivas, D.
- Chateigner, P. Bordet, and J. Chenavas, Phys. Rev. B 45, 4729 (1992).
- <sup>4</sup>S. B. Oseroff, D. Rao, F. Wright, M. Tovar, D. C. Vier, S. Schultz, J. D. Thompson, Z. Fisk, and S.-W. Cheong, Phys. Rev. B 41, 1934 (1990).
- <sup>5</sup>A. Butera, A. Caneiro, M. T. Causa, L. B. Steren, R. Zysler, M. Tovar, and S. B. Oseroff, Physica C 160, 341 (1989).
- <sup>6</sup>A. Rouco, X. Obradors, M. Tovar, P. Bordet, D. Chateigner, and J. Chenavas, Europhys. Lett. **20**, 651 (1992).
- <sup>7</sup>H. Müller-Buschbaum and W. Wollschlagger, Z. Anorg. Allg. Chem. **414**, 76 (1975).
- <sup>8</sup>The depression of  $T_N$  in single crystals may be due to a small (less than 1%) Pt contamination; Z. Fisk (private communication).
- <sup>9</sup>L. B. Steren, M. Tovar, and S. B. Oseroff, Phys. Rev. B 46, 2874 (1992).
- <sup>10</sup> A. Fainstein, M. Tovar, and Z. Fisk, J. Phys. Condensed Matter 4, 1581 (1992).
- <sup>11</sup> A. S. Borovick-Romanov and V. I. Ozhogin, Zh. Eksp. Teor. Fiz. **39**, 27 (1960) [Sov. Phys. JETP **12**, 18 (1961)].
- <sup>12</sup>T. Thio, T. R. Thurston, N. W. Preyer, P. J. Piccone, M. A. Kastner, H. P. Jenssen, D. R. Gabbe, C. Y. Chen, R. J. Birgeneau, and A. Aharony, Phys. Rev. B 38, 905 (1988).